## NSN 5961-01-075-9604



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-075-9604 **Inclosure Material:** Ceramic or glass or metal or plastic **Overall Length:** Between 0.340 inches and 0.380 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.056 inches and 0.075 inches **Mounting Method: Terminal Terminal Circle Diameter:** 0.018 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 400.0 breakdown voltage, collector-to-emitter, with specified circuit between base and emitter **Current Rating Per Characteristic:** 200.00 milliamperes forward current, average absolute **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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